

18-349: Introduction to Embedded Real-Time Systems

Lecture 1: Overview

Anthony Rowe

Electrical and Computer Engineering
Carnegie Mellon University



Electrical & Computer
ENGINEERING

Carnegie Mellon University

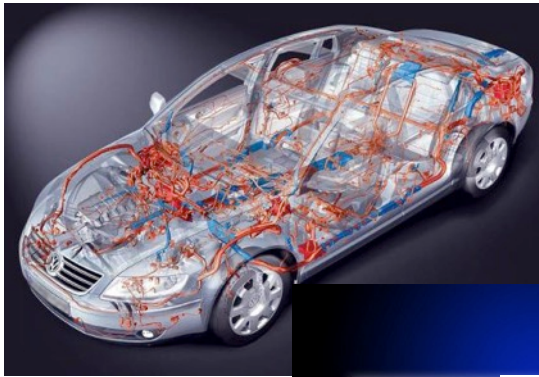
What is an embedded system?

An introduction



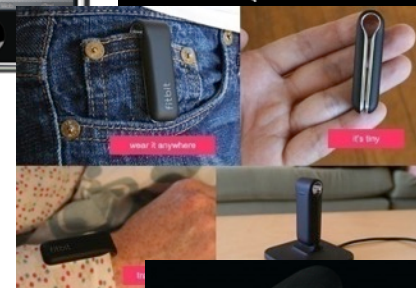
- Computer system hidden (embedded) in other systems
 - Often interacts with the physical environment
- Purpose built
- End users see “smart” device rather than computer
- Special-purpose vs. general-purpose computing

Embedded, Everywhere

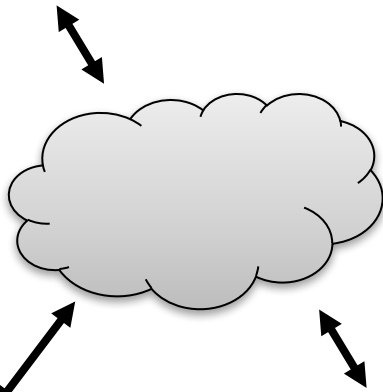


TEXAS INSTRUMENTS MSP430

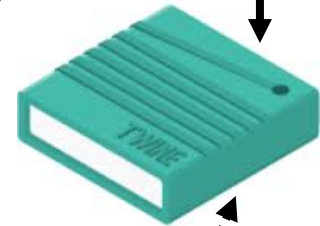
eZ430-Chronos Wireless Development Tool



Embedded, Everywhere - Internet of Things



People Connecting
Through Machines

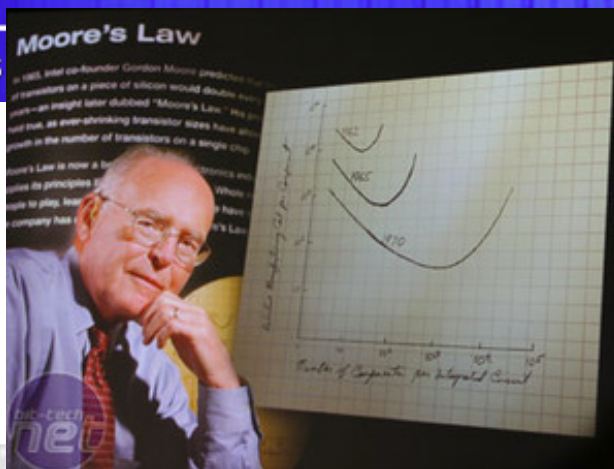



















Machines Connecting to Machines
and the Physical Environment

Embedded in Your Daily Life

- How many micro-controllers are around you?
 - Bathroom scale with digital read out
 - Iron that turns itself off automatically
 - Electronic toothbrush (with ~3000 lines of code)
 - Cooking range
 - Laundry machine and dryer
 - Toaster
 - Microwave
 - Home-security
 - TV, cable-box, AV system
 - Game console
 - Thermostat
 - Cars, Toys, Medical Devices...

What is driving the embedded explosion?



 <p>Intel® Atom™ D500 processor Intel Core™ Atom™ D500 processor Intel Atom™ D500 Intel Atom™ D500 Intel Atom™ D500</p> <p>2.66 GHz 582,000,000 65nm</p>	 <p>Intel® Atom™ D500 processor Intel Core™ Atom™ D500 processor Intel Atom™ D500 Intel Atom™ D500 Intel Atom™ D500</p> <p>3.2 GHz 291,000,000 65nm</p>	 <p>Intel® Atom™ D500 processor Intel Core™ Atom™ D500 processor Intel Atom™ D500 Intel Atom™ D500 Intel Atom™ D500</p> <p>1.7 GHz 55,000,000 90nm</p>	 <p>Intel® Atom™ D500 processor Intel Core™ Atom™ D500 processor Intel Atom™ D500 Intel Atom™ D500 Intel Atom™ D500</p> <p>1.5 GHz 42,000,000 90nm</p>	 <p>Intel® Atom™ D500 processor Intel Core™ Atom™ D500 processor Intel Atom™ D500 Intel Atom™ D500 Intel Atom™ D500</p> <p>500 MHz 9,500,000 0.18μ</p>
 <p>Intel® Atom™ D500 processor Intel Core™ Atom™ D500 processor Intel Atom™ D500 Intel Atom™ D500 Intel Atom™ D500</p> <p>> 3 GHz 820,000,000 45nm</p>	 <p>Intel® Atom™ D500 processor Intel Core™ Atom™ D500 processor Intel Atom™ D500 Intel Atom™ D500 Intel Atom™ D500</p> <p>1.66 GHz 1,200,000,000 90nm</p>	 <p>Intel® Atom™ D500 processor Intel Core™ Atom™ D500 processor Intel Atom™ D500 Intel Atom™ D500 Intel Atom™ D500</p> <p>2.93 GHz 291,000,000 65nm</p>	 <p>Intel® Atom™ D500 processor Intel Core™ Atom™ D500 processor Intel Atom™ D500 Intel Atom™ D500 Intel Atom™ D500</p> <p>1 GHz 220,000,000 0.13μ</p>	 <p>Intel® Atom™ D500 processor Intel Core™ Atom™ D500 processor Intel Atom™ D500 Intel Atom™ D500 Intel Atom™ D500</p> <p>300 MHz 7,500,000 0.25μ</p>
 <p>Intel® Atom™ D500 processor Intel Core™ Atom™ D500 processor Intel Atom™ D500 Intel Atom™ D500 Intel Atom™ D500</p> <p>66 MHz 3,100,000 0.8μ</p>	 <p>Intel® Atom™ D500 processor Intel Core™ Atom™ D500 processor Intel Atom™ D500 Intel Atom™ D500 Intel Atom™ D500</p> <p>25 MHz 1,200,000 1μ</p>	 <p>Intel® Atom™ D500 processor Intel Core™ Atom™ D500 processor Intel Atom™ D500 Intel Atom™ D500 Intel Atom™ D500</p> <p>6 MHz 134,000 1.5μ</p>	 <p>Intel® Atom™ D500 processor Intel Core™ Atom™ D500 processor Intel Atom™ D500 Intel Atom™ D500 Intel Atom™ D500</p> <p>500-800 KHz 3,500 10μ</p>	 <p>Intel® Atom™ D500 processor Intel Core™ Atom™ D500 processor Intel Atom™ D500 Intel Atom™ D500 Intel Atom™ D500</p> <p>200 MHz 5,500,000 0.6μ</p>
 <p>Intel® Atom™ D500 processor Intel Core™ Atom™ D500 processor Intel Atom™ D500 Intel Atom™ D500 Intel Atom™ D500</p> <p>16 MHz 275,000 1.5μ</p>	 <p>Intel® Atom™ D500 processor Intel Core™ Atom™ D500 processor Intel Atom™ D500 Intel Atom™ D500 Intel Atom™ D500</p> <p>5 MHz 29,000 3μ</p>	 <p>Intel® Atom™ D500 processor Intel Core™ Atom™ D500 processor Intel Atom™ D500 Intel Atom™ D500 Intel Atom™ D500</p> <p>5 MHz 29,000 3μ</p>	 <p>Intel® Atom™ D500 processor Intel Core™ Atom™ D500 processor Intel Atom™ D500 Intel Atom™ D500 Intel Atom™ D500</p> <p>2 MHz 4,500 6μ</p>	 <p>Intel® Atom™ D500 processor Intel Core™ Atom™ D500 processor Intel Atom™ D500 Intel Atom™ D500 Intel Atom™ D500</p> <p>108 KHz 2,300 10μ</p>

Flash memory scaling: Rise of density & volumes; Fall (and rise) of prices

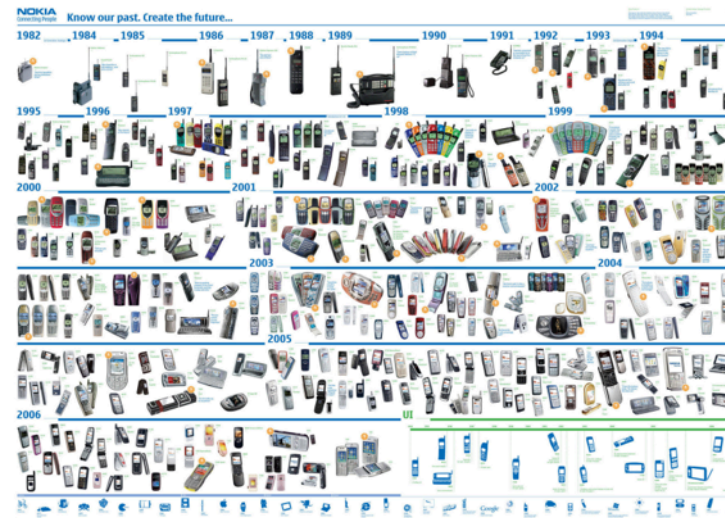
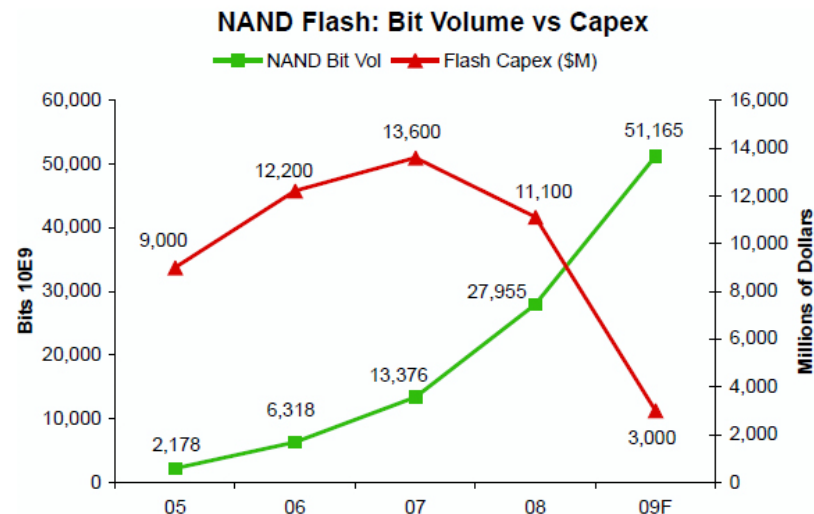
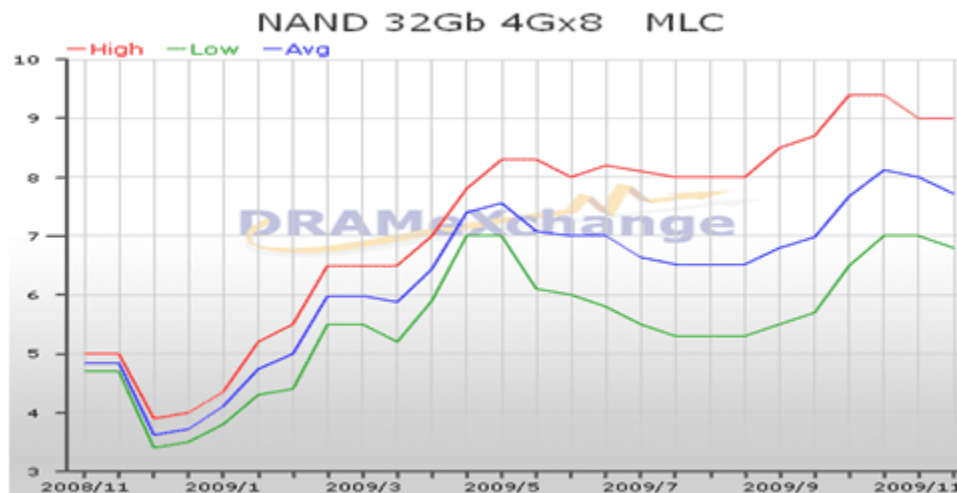
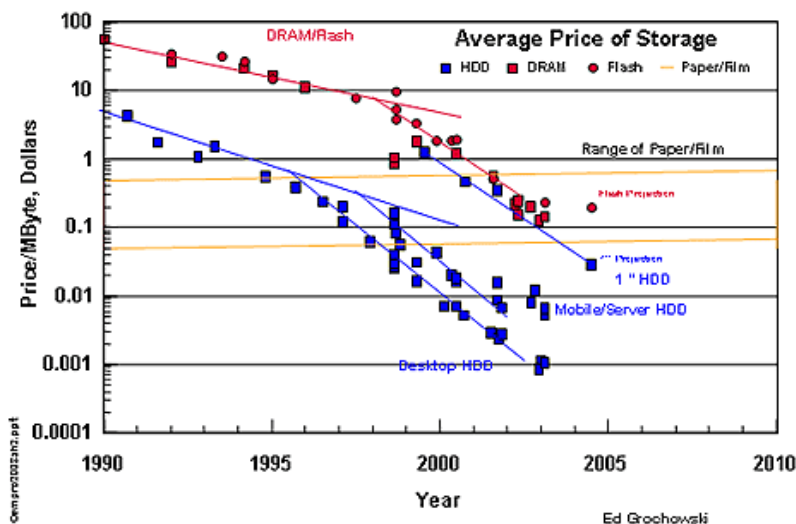
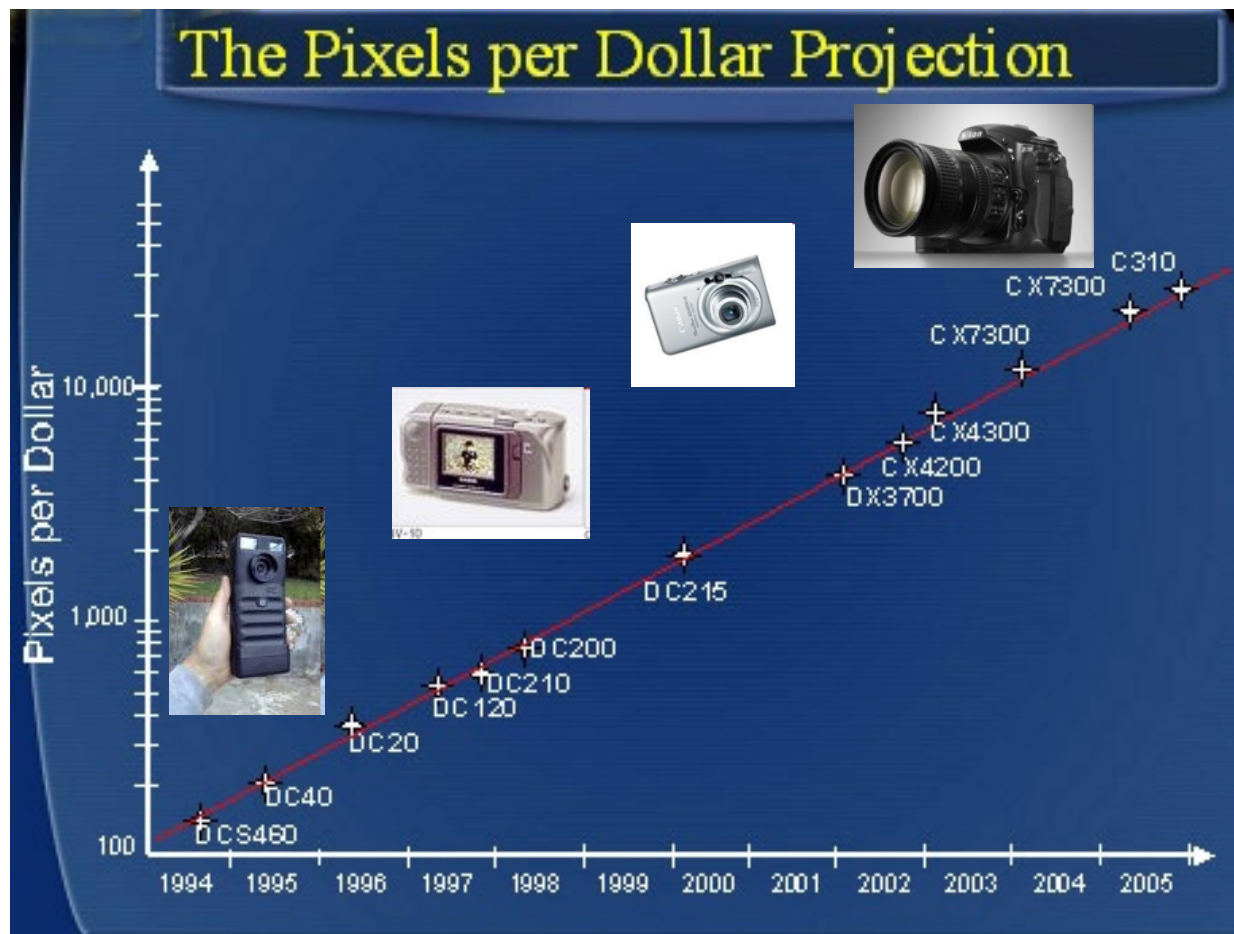


Figure-1 32Gb MLC NAND Flash contract price trend



Hendy's "Law": Pixels per dollar doubles annually



Dennard Scaling made transistors fast and low-power: So everything got better!



Design of Ion-Implanted MOSFET's with Very Small Physical Dimensions

ROBERT H. DENNARD, MEMBER, IEEE, FRITZ H. GAENSSLEN, HWA-NIEN YU, MEMBER, IEEE, V. LEO RIDEOUT, MEMBER, IEEE, ERNEST BASSOUS, AND ANDRE R. LEBLANC, MEMBER, IEEE

Classic Paper

This paper considers the design, fabrication, and characterization of very small MOSFET switching devices suitable for digital integrated circuits using dimensions of the order of 1μ . Scaling relationships are presented which show how a conventional MOSFET can be reduced in size. An improved small device structure is presented that uses ion implantation to provide shallow source and drain regions and a nonuniform substrate doping profile. One-dimensional models are used to predict the substrate doping profile and the corresponding threshold voltage versus source voltage characteristic. A two-dimensional current transport model is used to predict the relative degree of short-channel effects for different device parameter combinations. Polysilicon-gate MOSFET's with channel lengths as short as 0.5μ were fabricated, and the device characteristics measured and compared with predicted values. The performance improvement expected from using these very small devices in highly miniaturized integrated circuits is projected.

q	Charge on the electron.
Q_{eff}	Effective oxide charge.
t_{ox}	Gate oxide thickness.
T	Absolute temperature.
$V_d, V_s, V_g, V_{\text{sub}}$	Drain, source, gate and substrate voltages.
V_{ds}	Drain voltage relative to source.
$V_{s-\text{sub}}$	Source voltage relative to substrate.
V_t	Gate threshold voltage.
w_s, w_d	Source and drain depletion layer widths.
W	MOSFET channel width.

I. LIST OF SYMBOLS

α	Inverse semilogarithmic slope of sub-threshold characteristic.
D	Width of idealized step function profile for channel implant.
ΔW_f	Work function difference between gate and substrate.
$\epsilon_{\text{Si}}, \epsilon_{\text{ox}}$	Dielectric constants for silicon and silicon dioxide.
I_d	Drain current.
k	Boltzmann's constant.
n	Unitless scaling constant.
L	MOSFET channel length.
μ_{eff}	Effective surface mobility.
n_i	Intrinsic carrier concentration.
N_a	Substrate acceptor concentration.
Ψ_s	Band bending in silicon at the onset of strong inversion for zero substrate voltage.
Ψ_b	Built-in junction potential.

This paper is reprinted from IEEE JOURNAL OF SOLID-STATE CIRCUITS, vol. SC-9, no. 5, pp. 256-268, October 1974.
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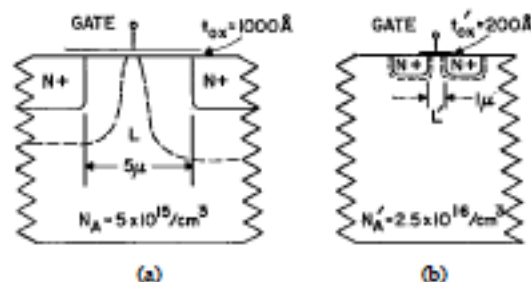
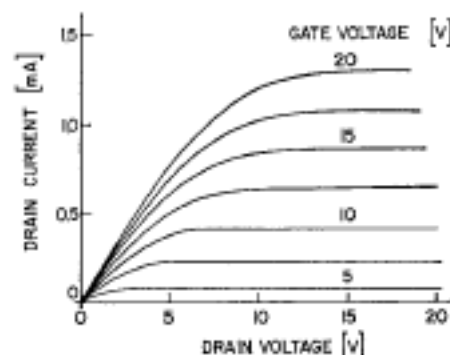
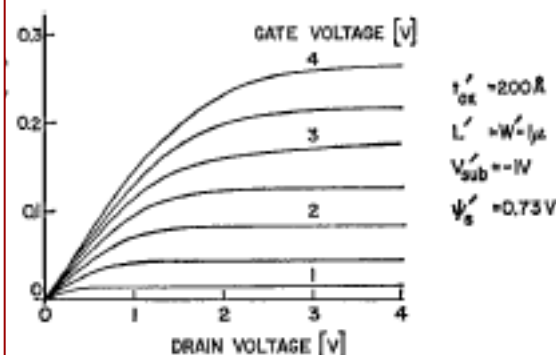


Fig. 1. Illustration of device scaling principles with $\kappa = 5$. (a) Conventional commercially available device structure. (b) Scaled-down device structure.

portion of the region in the silicon substrate under the gate electrode. For switching applications, the most undesirable "short-channel" effect is a reduction in the gate threshold voltage at which the device turns on, which is aggravated



(a)

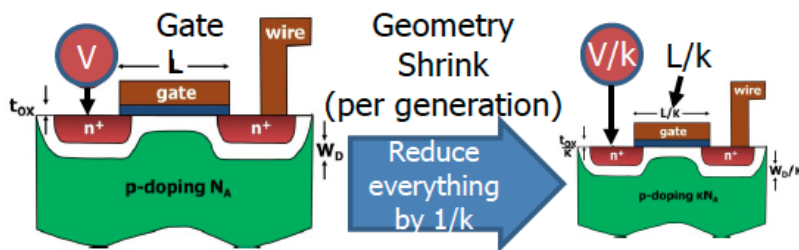


(b)

Fig. 2. Experimental drain voltage characteristics for (a) conventional, and (b) scaled-down structures shown in Fig. 1 normalized to $W/L = 1$.



The past: Dennard's Scaling



$$P_{\text{density}} = N_g C_{\text{load}} V^2 f$$

= power per unit area

N_g = CMOS gates/unit area

C_{load} = capacitive load/CMOS gate

V = supply voltage

f = clock frequency

k = scaling factor

k = typically 1.4 per geometry shrink

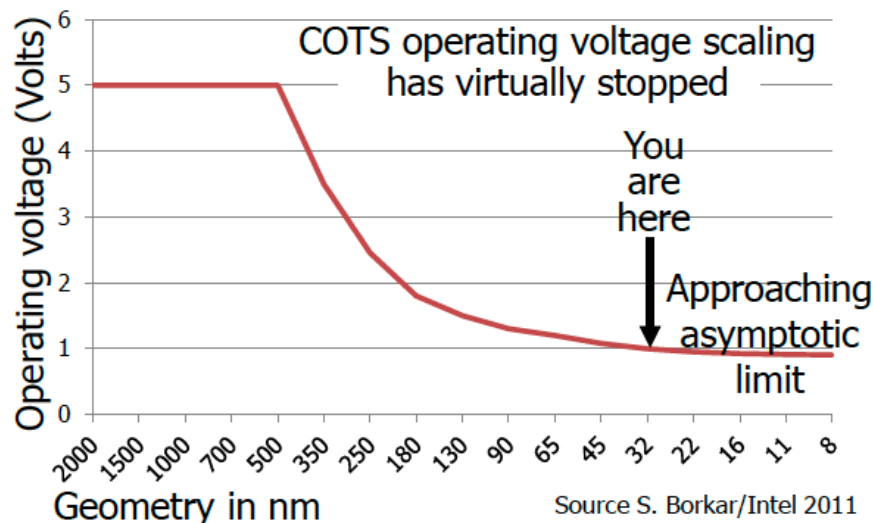
$1/k$ = device feature scaling factor
(typically 0.7 per geometry shrink)

For each generation/geometry shrink:

$$P_{\text{density (scaling)}} = (k^2)(1/k)(1/k^2)(k) = 1$$

Double the transistors (functionality) and increase the clock speed 40% per generation with the same power

Today: Dennard's Scaling is dead



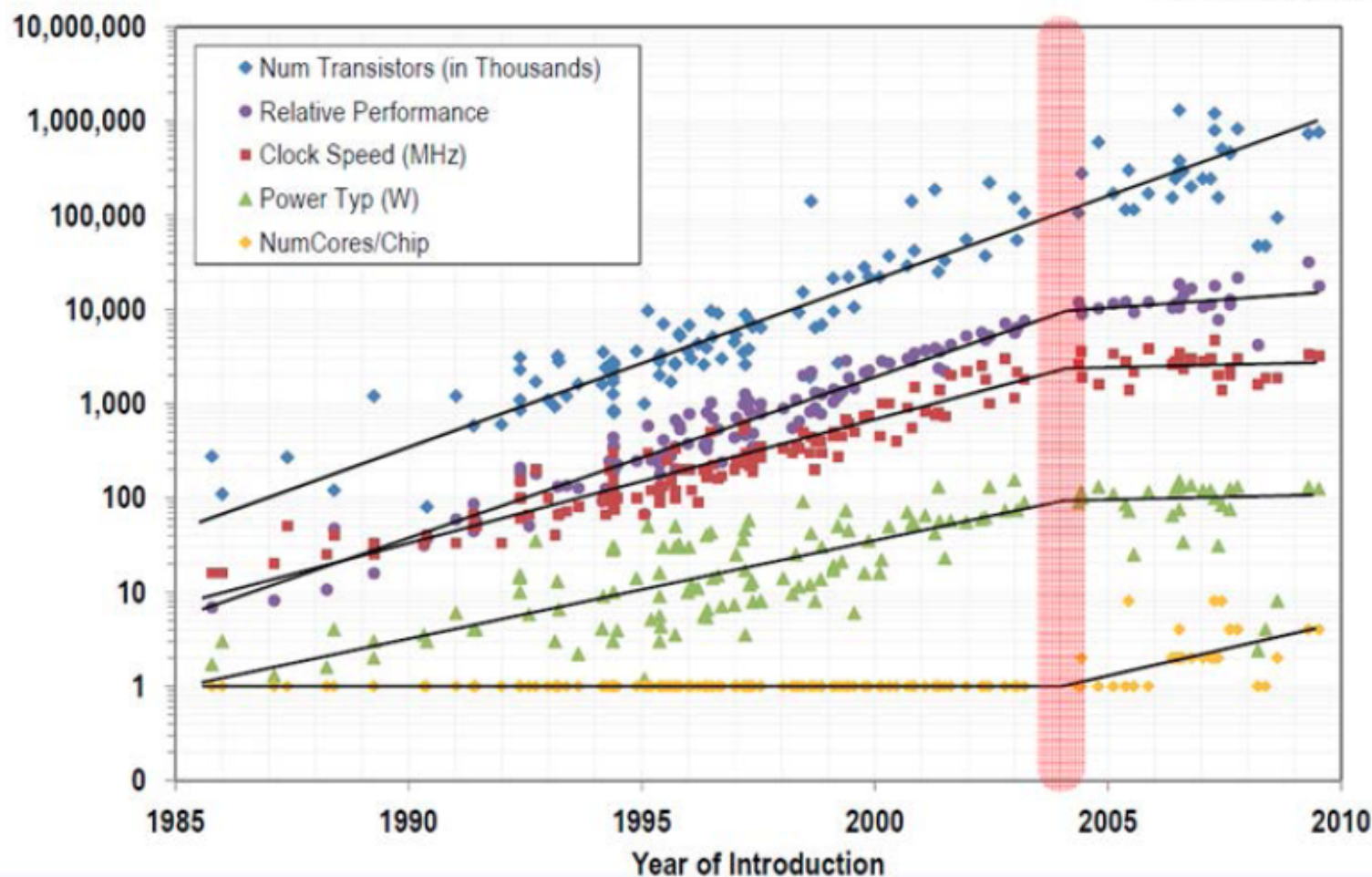
$$P_{\text{density (scaling)}} = (k^2)(1/k)(\cancel{1/k^2})(k) = k^2 \cong 2$$

But, power density cannot increase!

This physics is limiting COTS power efficiency to well below what we need for embedded sensor processing applications

Decades of exponential performance growth stalled in 2004

NATIONAL ACADEMIES



Source: NRC, The Future of Computing Performance, Game Over or Next Level?

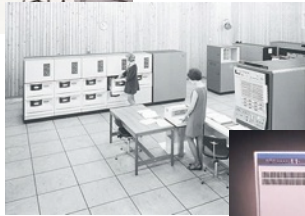
Not so fast! Bell's Law of Computer Classes: A new computing class roughly every decade



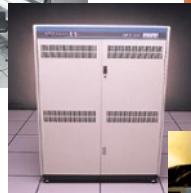
log (people per computer)



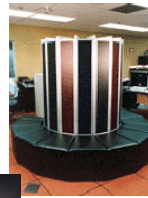
Mainframe



Minicomputer



Workstation



PC



Laptop



CPSD



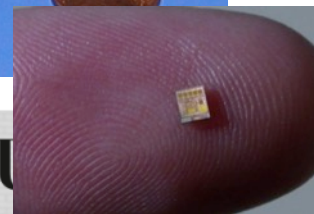
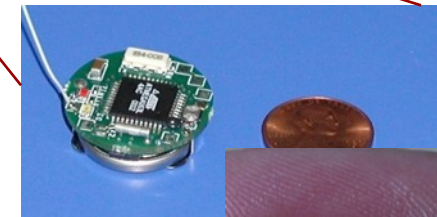
Number Crunching
Data Storage

productivity
interactive

Streaming information
to/from physical world

year

"Roughly every decade a new, lower priced computer class forms based on a new programming platform, network, and interface resulting in new usage and the establishment of a new industry."



Technology Trends



- Multi-core embedded with SoC
- Better, cheaper, lower power sensors
- Better communication
 - Bluetooth Low-Energy
 - 802.15.4
 - 802.11 AC
- Energy Harvesting



Why is embedded different?

Typical Embedded System Challenges (1-2)

- Small Size, Low Weight
 - Handheld electronics
 - Transportation applications weight costs money
- Low Power
 - Battery power for 8+ hours (laptops often last only 2 hours)
 - Limited cooling may limit power even if AC power available



Typical Embedded System Challenges (2-2)

- Harsh environment
 - Heat, vibration, shock
 - Power fluctuations, RF interference, lightning
 - Water, corrosion, physical abuse
- Safety-critical operation
 - Must function correctly
 - Must not function incorrectly
- Extreme cost sensitivity
 - \$.05 adds up over 1,000,000 units



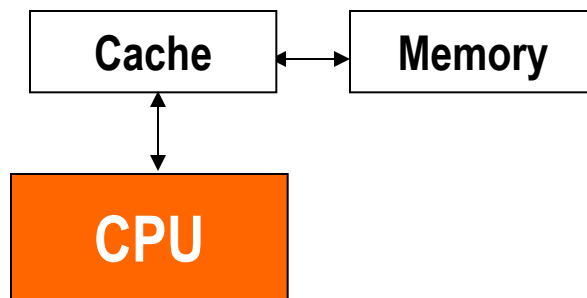
CPU: An All Too Common View of Computing

- Measured by: Performance



An Advanced Computer Engineer's View

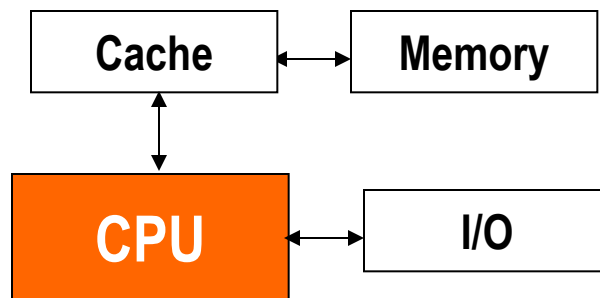
- **Measured by: Performance**
 - Compilers matter too...



An Enlightened Computer Engineer's View

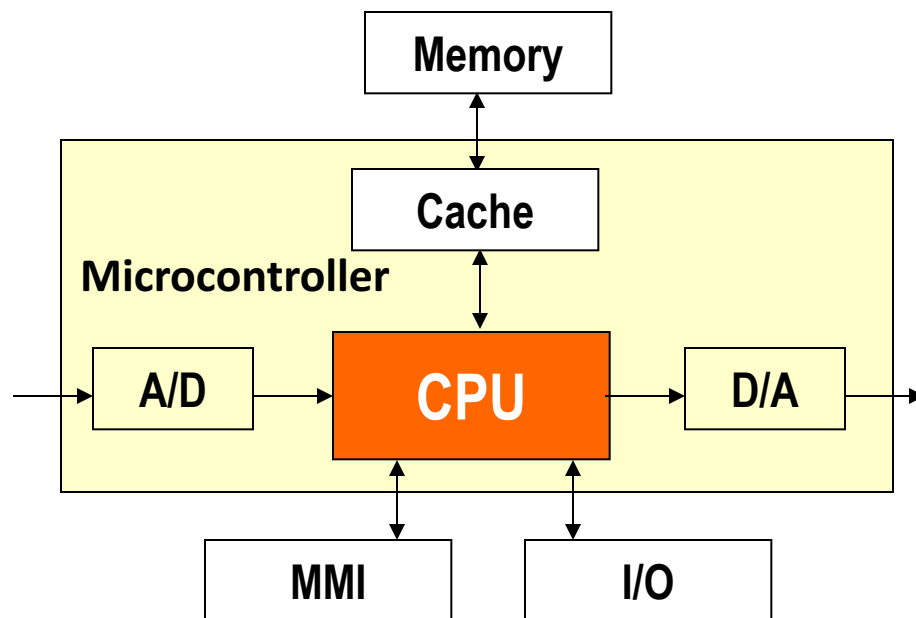
■ Measured by: Performance, Cost

- Compilers & OS matter



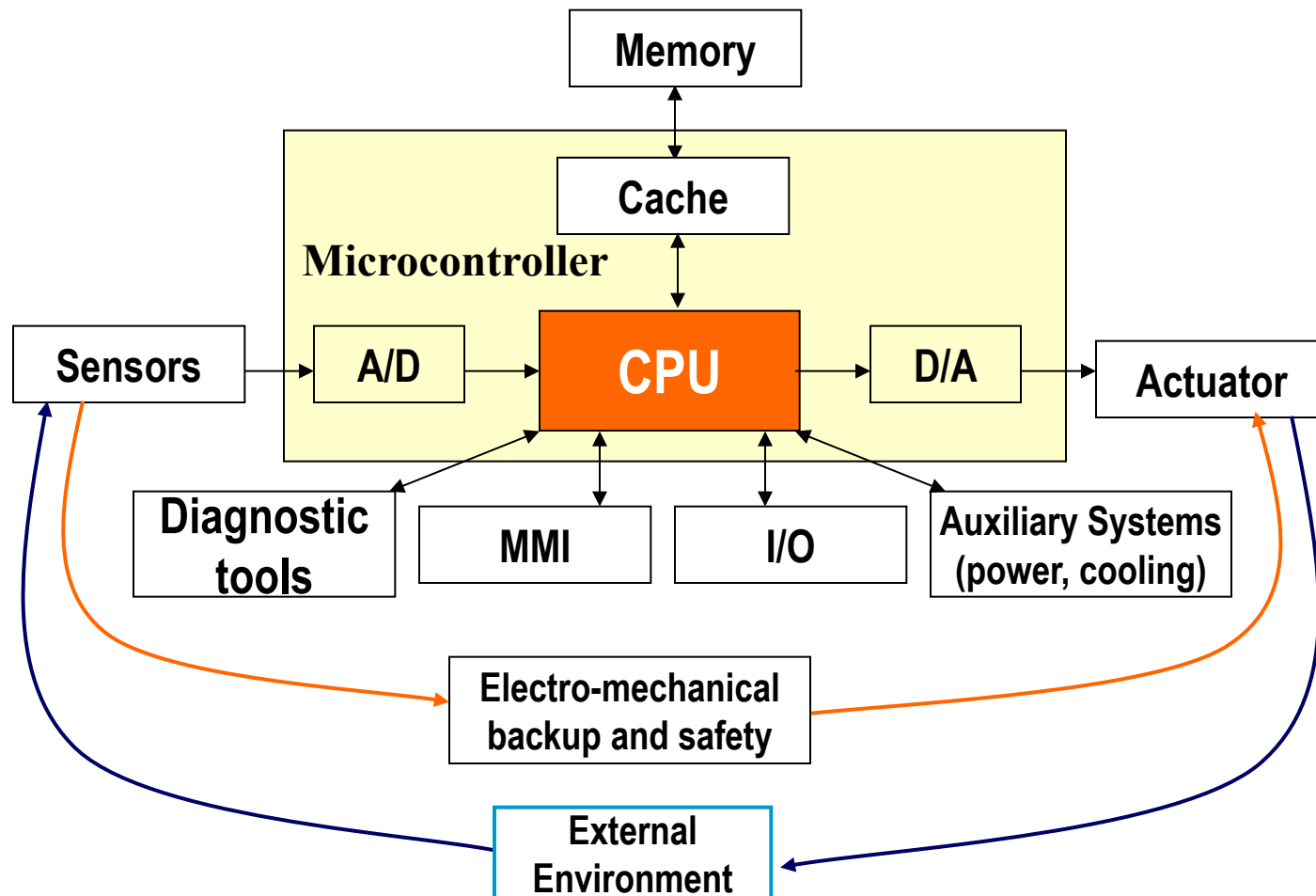
An Embedded Computer Designer's View

- Measured by: Cost, I/O connections, Memory Size, Performance



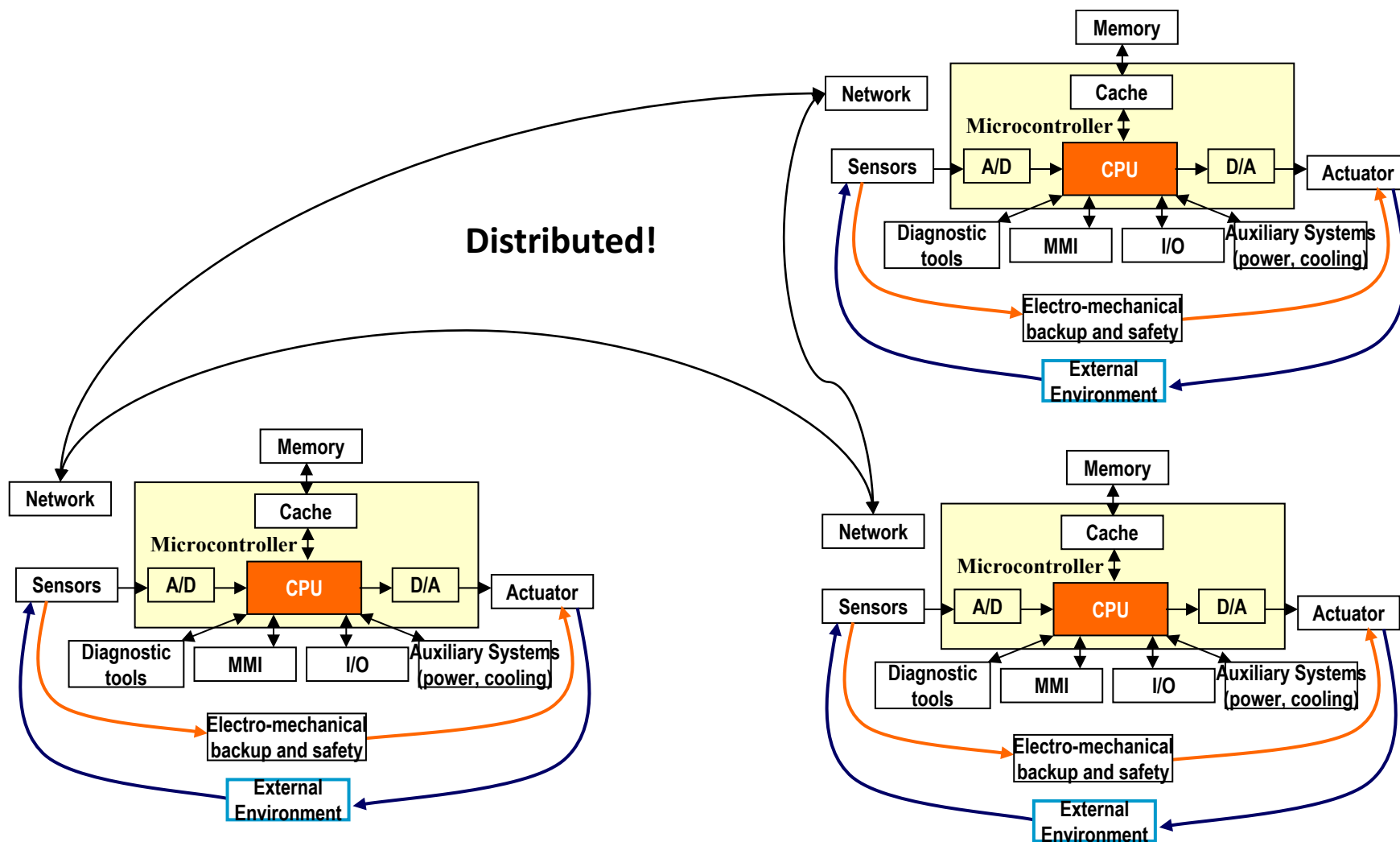
An Embedded Application Designer's View

- Measured by: Cost, Timetomarket, Cost, Functionality, Cost & Cost.



Modern Embedded Systems View

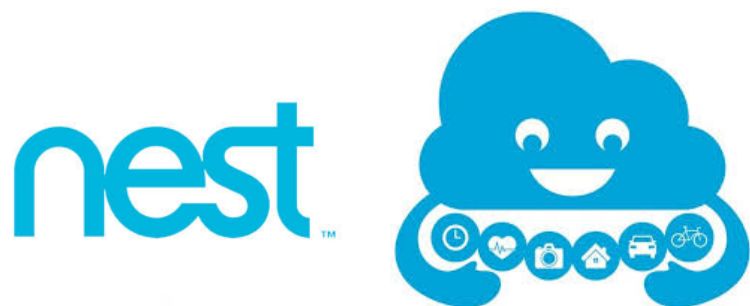
- Measured by: Does it actually work? (and all of the other stuff)



Embedded Computers *Rule* the Marketplace

- ~80 Million PCs vs. ~3 Billion Embedded CPUs annually
 - Embedded market growing; PC market *mostly* saturated
- Domain Experts Needed...
 - **General Computing**
 - Set-top boxes, video game consoles, ATM, ...
 - **Control Systems**
 - Airplane, Heating and Cooling System
 - **Signal Processing**
 - Radar, Sonar, Video Compression, Human-Brain interface
 - **Communication**
 - Internet, Wireless Communication, VoIP...

Embedded Systems Careers



TESLA MOTORS

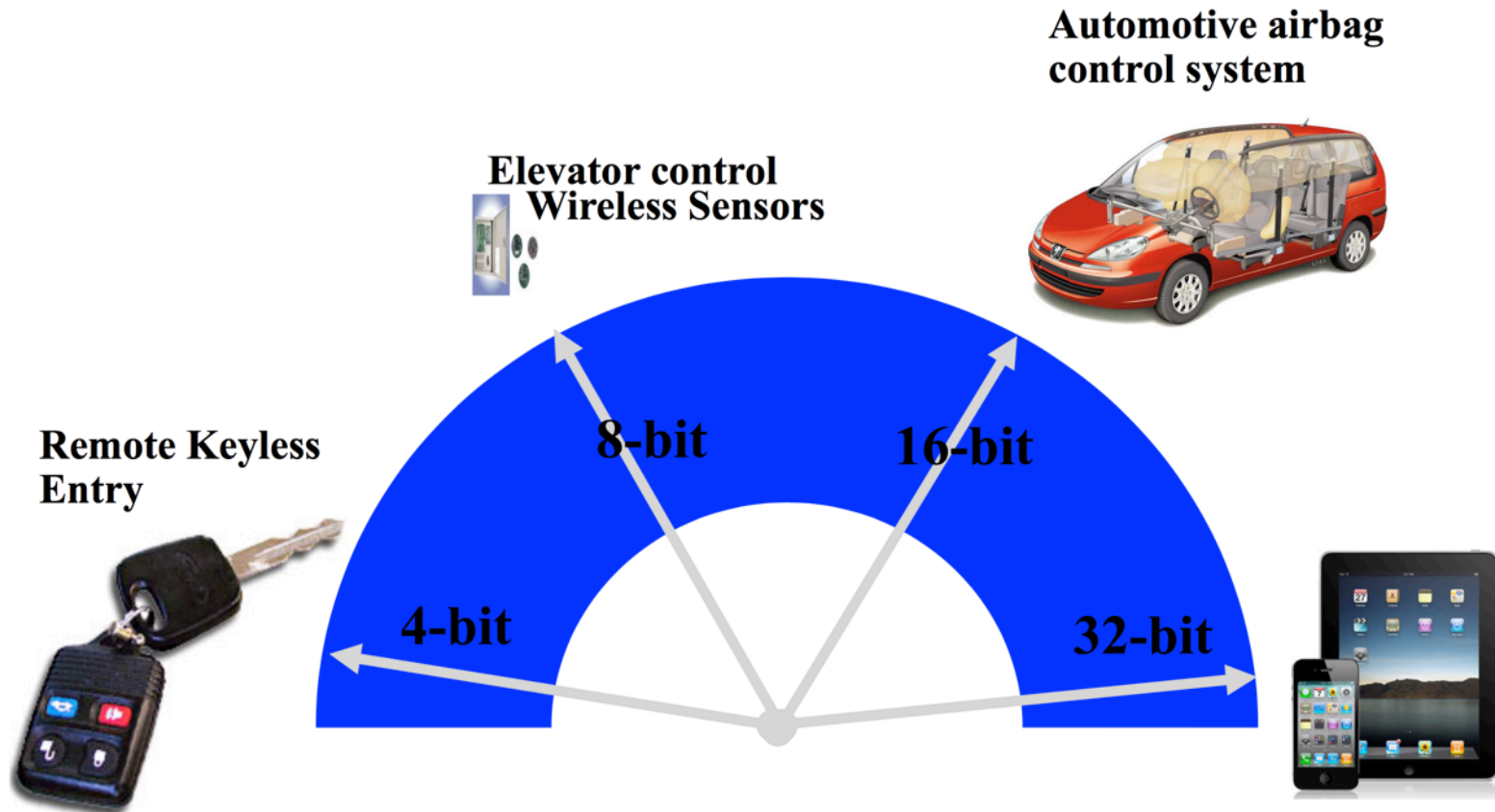


MICROCHIP



Misconceptions (1)

- Embedded systems = low end microcontrollers



Misconceptions (2)



- Embedded system programming = programming in assembly to optimize the code for space, time etc.
- Compilers are typically better than humans at generating the best code
- Code portability issues -> some device-driver dependent code written in assembly, but most app code is written in higher-level languages

Misconceptions (3)



- Embedded systems = old topic
- Always new and exciting developments that track technology
 - New sensors / actuators
 - More powerful chips
 - New communication mechanisms
- Embedded systems + Internet = Internet of Things
 - Massively hot topic right now!